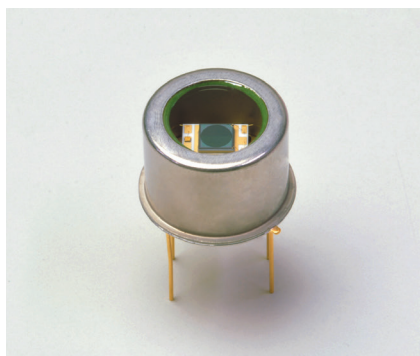


# MPPC® (Multi-Pixel Photon Counter)



S14422 series

## High sensitivity, low noise MPPC for visible and near infrared region

MPPC, also called Si PM (silicon photomultipliers), is a new type of photon counting device that consists of multiple Geiger mode APD (avalanche photodiode) pixels. It is an opto-semiconductor with outstanding photon counting capability and low operating voltage and is immune to the effects of magnetic fields.

The S14422 series is an MPPC for the visible to near infrared region. It provides higher photon detection efficiency than the previous product (S13362 series) in the visible to near infrared region. In addition, the built-in TE-cooler function provides low crosstalk and low afterpulses as well as reduces the dark count to 1/10 that of the non-cooled type (S14420 series).

### Features

- Low dark count: 1/10 that of the non-cooled type (-10 °C)
- High photon detection efficiency: 40% ( $\lambda=600$  nm,  $V_{op}=V_{BR} + 5$ , 50  $\mu$ m pitch)
- Low crosstalk, low afterpulses
- Low voltage ( $V_{BR}=40.5$  V typ.) operation (-10 °C)
- High gain:  $10^5$  to  $10^6$
- Operates with simple readout circuit
- MPPC module also available (sold separately)

### Applications

- Flow cytometry
- Laser scan microscope
- Fluorescence measurement

### Structure

Parameter	S14422-1525DG	S14422-1550DG	S14422-3025DG	S14422-3050DG	Unit
Pixel pitch	25	50	25	50	$\mu$ m
Effective photosensitive area	$\phi 1.5$		$\phi 3.0$		mm
Number of pixels	2876	724	11344	2836	-
Fill factor	63	81	63	81	%
Package	Metal (TO-8)				-
Window material	Borosilicate glass				-
Window refractive index	1.52				-
Cooling	Two-stage TE-cooled				-

### Absolute maximum ratings

Parameter	Symbol	S14422-1525DG	S14422-1550DG	S14422-3025DG	S14422-3050DG	Unit
Operating temperature*1	Topr	-20 to +60				°C
Storage temperature*1	Tstg	-20 to +85				°C
Chip temperature	Tchip	-25 to ambient temperature				°C
Thermistor power dissipation	Pd_th	0.2				mW
Allowable TE-cooler current	ITE max	1				A
Allowable TE-cooler voltage	VTE max	0.9				V
Soldering conditions*2	Tsol	Peak temperature: 350 °C*3, once, 3 s max.				-

\*1: No dew condensation

When there is a temperature difference between a product and the surrounding area in high humidity environment, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

\*2: At least 1 mm away from lead roots

\*3: Soldering iron tip

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

**Electrical and optical characteristics (Typ. Ta=25 °C, Tchip=-10 °C, unless otherwise noted)**

Parameter	Symbol	S14422-1525DG	S14422-1550DG	S14422-3025DG	S14422-3050DG	Unit
Spectral response range	$\lambda$	350 to 1000				nm
Peak sensitivity wavelength	$\lambda_p$	600				nm
Photon detection efficiency*4	PDE	30	40	30	40	%
Dark count	Typ.	35				kcps
	Max.	90				
Terminal capacitance	Ct	90				pF
Gain	M	$0.9 \times 10^6$	$3.6 \times 10^6$	$0.9 \times 10^6$	$3.6 \times 10^6$	-
Breakdown voltage	VBR	$40.5 \pm 5$				V
Crosstalk probability	-	1.5	5	1.5	5	%
Recommended operating voltage*5	Vop	$V_{BR} + 5$				V
Temperature coefficient at recommended operating voltage	$\Delta T_{Vop}$	47				mV/°C
Recommended TE-cooler temperature	TTE_recom	-10				°C
Thermistor resistance*6	Rth	9				k $\Omega$
Thermistor B constant*7	B	3410				K

\*4:  $\lambda = \lambda_p$ , photon detection efficiency does not include crosstalk or afterpulses.

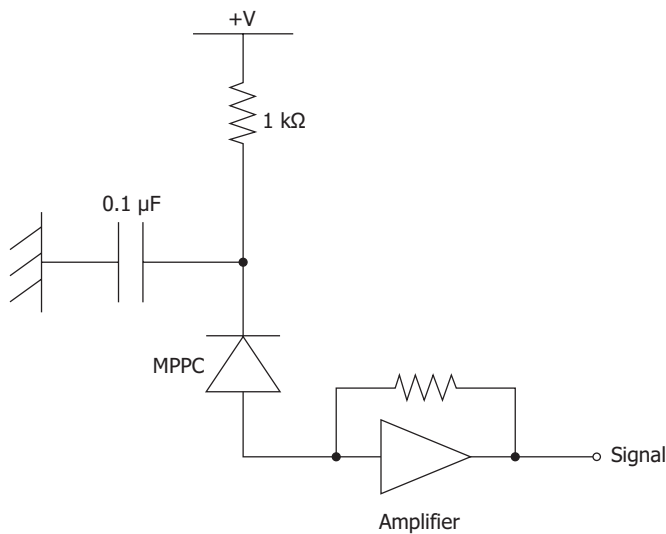
\*5: Refer to the data provided with the product.

\*6: Thermistor temperature=25 °C

\*7: T1=25 °C, T2=50 °C

Note: The above characteristics were measured at the operating voltage that yields the listed gain. (See the data attached to each product.)

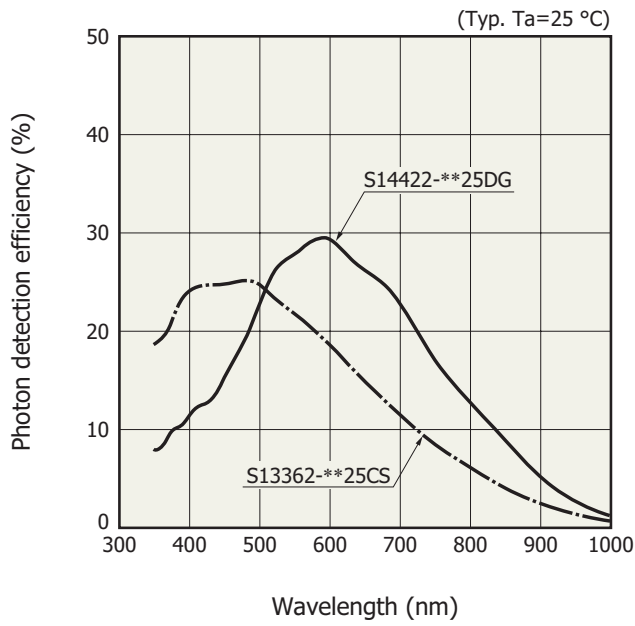
**Connection example**



KAPDC0024EB

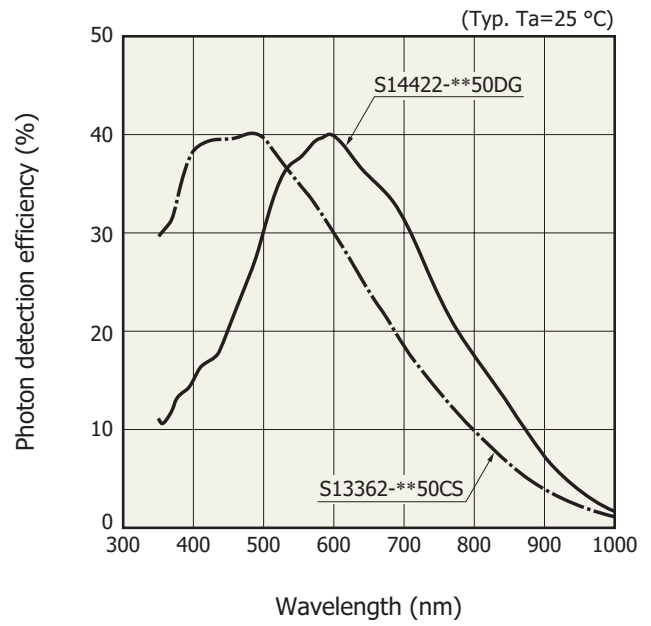
Photon detection efficiency vs. wavelength (typical example)

Pixel pitch: 25  $\mu\text{m}$



KAPDB0558EA

Pixel pitch: 50  $\mu\text{m}$

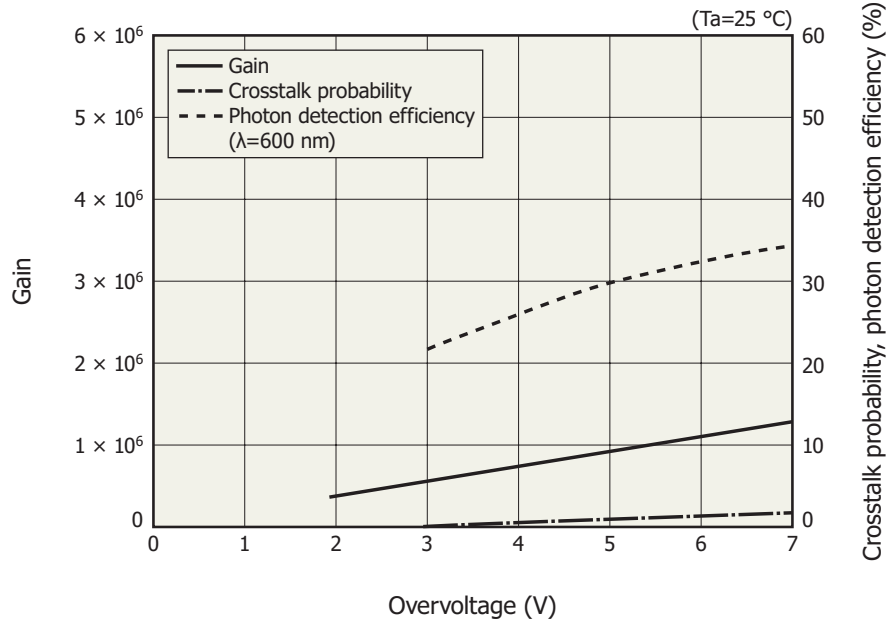


KAPDB0559EA

Photon detection efficiency does not include crosstalk or afterpulses.

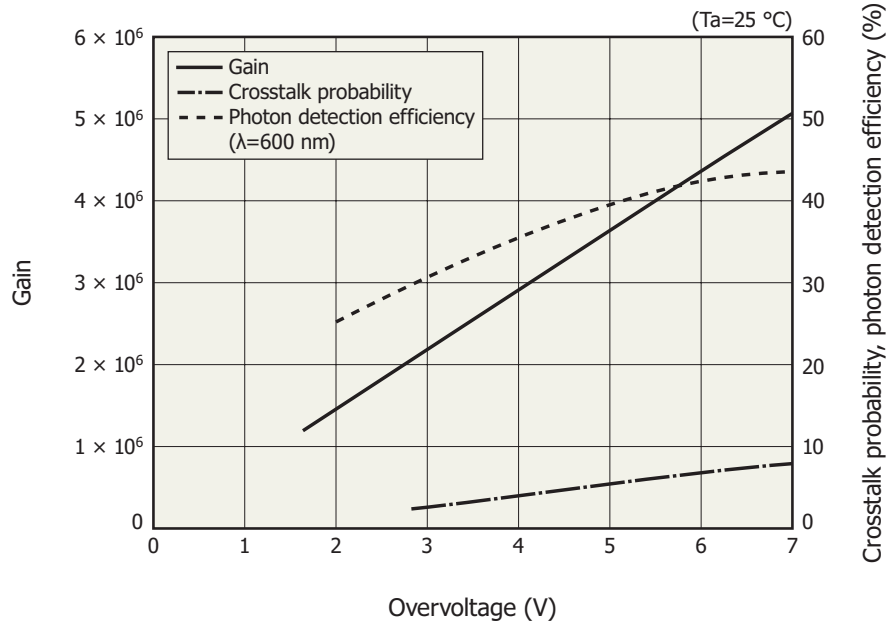
Gain, crosstalk probability, photon detection efficiency vs. overvoltage characteristics (typical example)

Pixel pitch: 25  $\mu\text{m}$



KAPDB0560EA

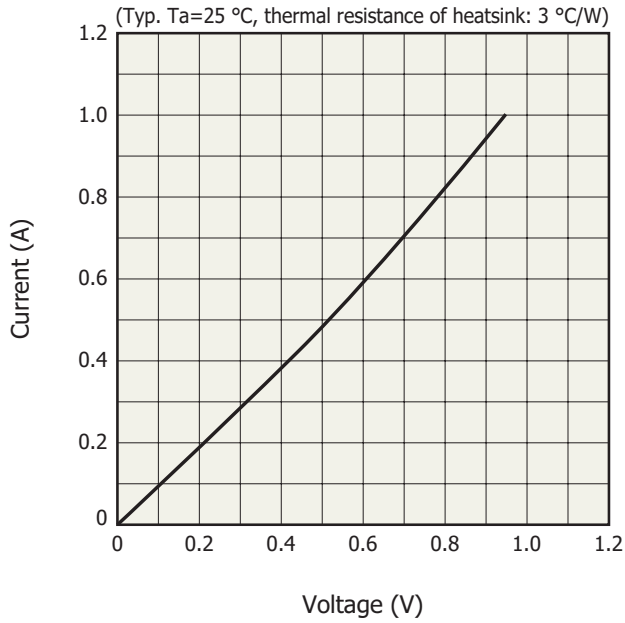
Pixel pitch: 50  $\mu\text{m}$



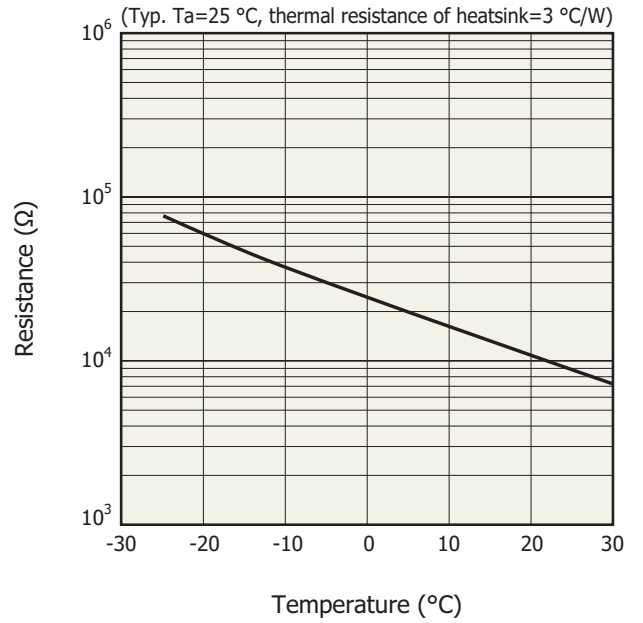
KAPD060561EA

MPPC characteristics vary with the operating voltage. Although increasing the operating voltage improves the photon detection efficiency and time resolution, it also increases the dark count and crosstalk at the same time, so an optimum operating voltage must be selected to match the application.

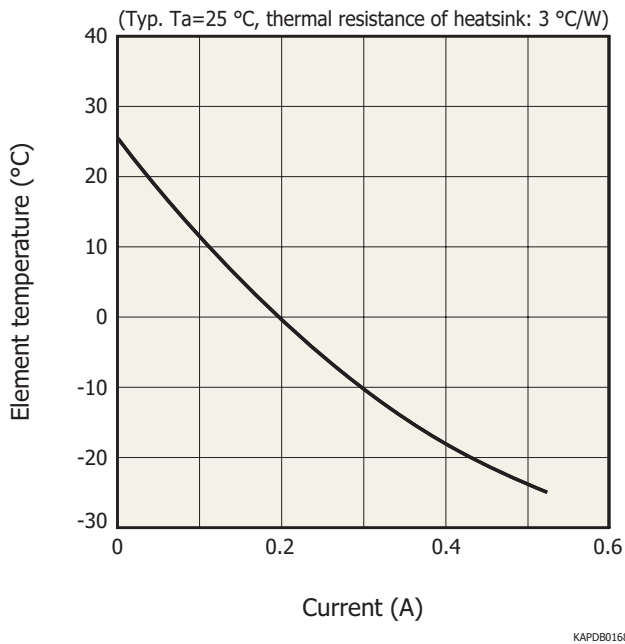
Current vs. voltage characteristics of TE-cooler



Thermistor temperature characteristics

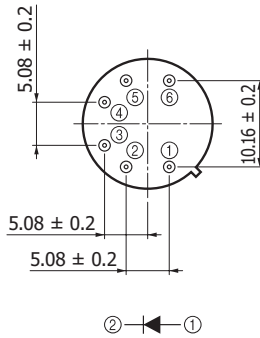
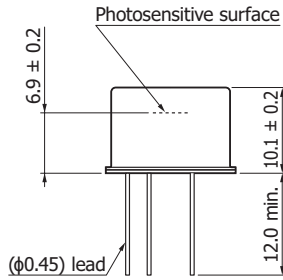
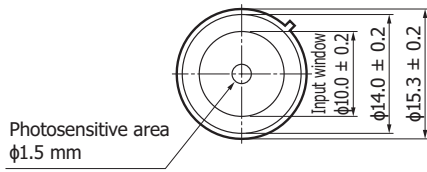


Cooling characteristics of TE-cooler



Dimensional outlines (unit: mm)

S14422-1525DG/-1550DG

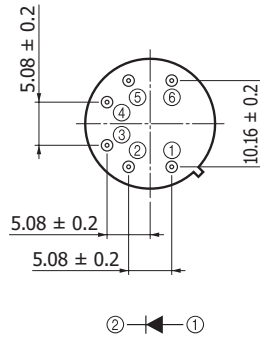
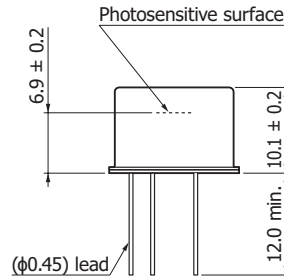
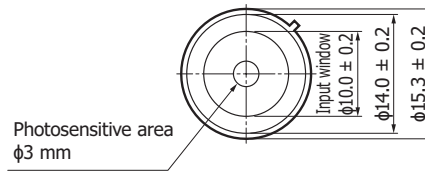


Tolerance unless otherwise noted:  $\pm 0.2$   
 Distance from photosensitive area center to cap center  
 $-0.3 \leq X \leq +0.3$   
 $-0.3 \leq Y \leq +0.3$

- ① Detector (anode)
- ② Detector (cathode)
- ③ TE-cooler (-)
- ④ TE-cooler (+)
- ⑤⑥ Thermistor

KAPDA0210EA

S14422-3025DG/-3050DG



Tolerance unless otherwise noted:  $\pm 0.2$   
 Distance from photosensitive area center to cap center  
 $-0.3 \leq X \leq +0.3$   
 $-0.3 \leq Y \leq +0.3$

- ① Detector (anode)
- ② Detector (cathode)
- ③ TE-cooler (-)
- ④ TE-cooler (+)
- ⑤⑥ Thermistor

KAPDA0211EA

## Precautions

- If necessary, incorporate appropriate protective circuits in power supplies, devices, and measuring instruments to prevent overvoltage and overcurrent.

## Related information

[www.hamamatsu.com/sp/ssd/doc\\_en.html](http://www.hamamatsu.com/sp/ssd/doc_en.html)

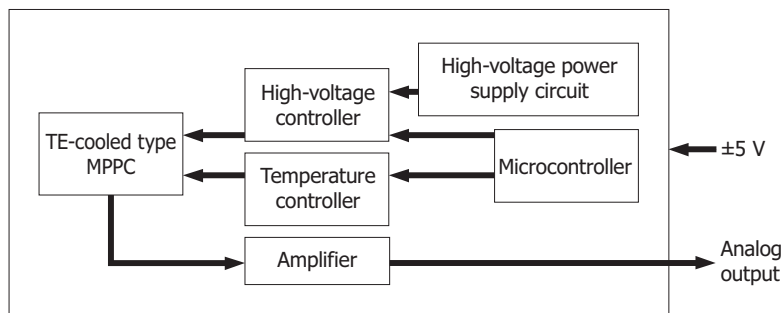
### Precautions

- Disclaimer
- Metal, ceramic, plastic package products

## MPPC modules C14455/C14456 series (GA type)

The C14455/C14456 series (GA type) are measurement modules capable of detecting low-level light using its built-in TE-cooled MPPC (S14422 series). These modules consist of a thermoelectrically cooled MPPC, an amplifier, a high-voltage power supply circuit, and a temperature control circuit. The photosensitive area is available in two sizes of  $\phi 1.5$  mm and  $\phi 3.0$  mm, and the signal output is analog. The modules operate just by connecting them to an external power supply ( $\pm 5$  V). As the C14456 series is compact and lightweight, it is suitable for integration into devices (Heat dissipation measures are necessary).

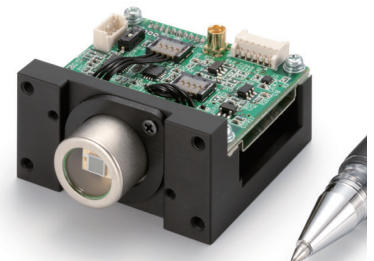
## Block diagram



KACCC0680EA



C14455 series (GA type)



C14456 series (GA type)

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Information described in this material is current as of September 2019.

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